■ MN103S83D

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Тур	Туре			MN103S83D		
Inte	Internal ROM			64K-byte		
Inte	Internal RAM			2K-byte		
Pac	Package			QFP084-P-1818E *Lead-free, LQFP080-P-1414A *Lead-free		
	imum Instru cution Time			25 ns (at 4.3 V to 5.5 V, 10 MHz internal regulator used) 25 ns (at 3.0 V to 3.6 V, 10 MHz) *at internal 4 times oscillation used)		
Inte	Interrupts			 9 external interrupts 40 internal interrupts (watch dog timer, timer, serial I/F, PWM, A/D, system error) 		
Tim	Timer Counter			8-bit timer × 8 Timer 0 to 7: Interval timer, Event counter, Cascading connectable		
				16-bit timer × 4 Timer 8: Interval timer, Event counter, PWM output (6 pins simultaneous output are available), Double buffer Timer 9, 10: Interval timer, Event counter, PWM output, Double buffer Timer 11: Interval timer, Double buffer, Start synchronized with 3-phase PWM are available Watch dog timer		
Ser	Serial Interface			UART (full duplex) / synchronous interfaces selective × 2 Serial 1: 7-bit, 8-bit transmission Serial 2: 1-bit to 8-bit transmission (synchronous), 2 and 3 channel type selectable (synchronous)		
I/O	Pins	I/O	50	Exclusive × 5, selective × 45		
		Input	10	Selective × 10		
A/D	A/D Inputs			10-bit × 2 unit, 2 inputs × 2, 6 inputs × 1 Simultaneous conversion of 3 series are available, With S/H, Conversion start synchronized with 3-phase PWM or timer 11 are available		
Mot	Motor Control PWM			16-bit 3-phase PWM × 1 Minimum resolution: 50 ns Triangular waveform or jigsaw waveform dead time setup, Double buffer, Output polar switching is available, PWM output pin protect function		
Not	Notes			5 V single power supply (Internal regulator)		

Electrical Characteristics

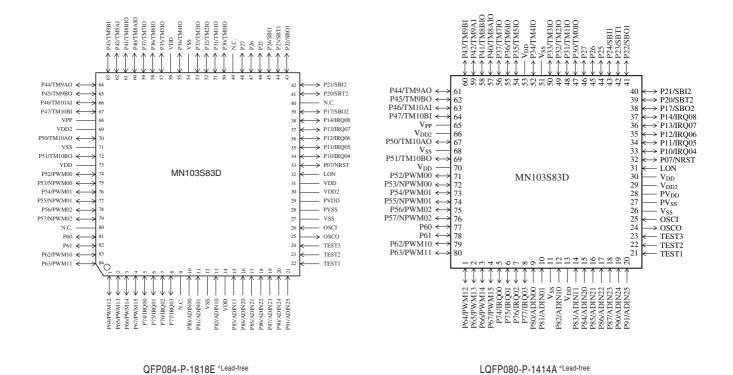
A/D converter characteristics

Parameter	Symbol	Condition	Limit			Unit
raiametei			min	typ	max	Oilit
Non-linear error		10-bit			±3	LSB
A/D conversion time	tAD		1.5			μs
Analog input voltage	VIA		VSS		VDD	V

 $(Ta = 25^{\circ}C, VDD = 5.0 \text{ V}, VSS = 0 \text{ V})$

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Pin Assignment



Support Tool

In-circuit Emulator	PX-ICE-103S65			
Flash Memory Built-in Type	Туре	MN103SF65GBF, MN103SF65GAL		
	ROM	128K-byte		
	RAM	4K-byte		
	Minimum instruction execution time	25 ns (at 4.3 V to 5.5 V, 10 MHz internal regulator used)		
		25 ns (at 3.0 V to 3.6 V, 10 MHz)		
	Package	QFP084-P-1818I *Lead-free, LQFP080-P-1414B *Lead-free		

MAF00014EEM Panasonic

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